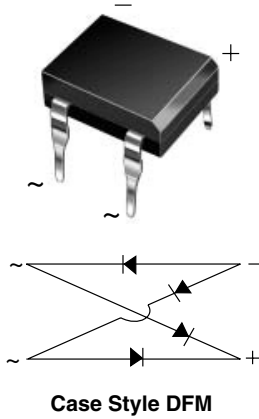


## Miniature Glass Passivated Single-Phase Bridge Rectifiers



### FEATURES

- UL recognition, file number E54214
- Ideal for printed circuit boards
- Applicable for automotive insertion
- High surge current capability
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC


**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

General purpose use in ac-to-dc bridge full wave rectification for SMPS, lighting ballaster, adapter, battery charger, home appliances, office equipment, and telecommunication applications.

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	1 A
$V_{RRM}$	50 V to 1000 V
$I_{FSM}$	50 A
$I_R$	5 $\mu$ A
$V_F$	1.1 V
$T_J$ max.	150 °C

### MECHANICAL DATA

**Case:** DFM

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

**Polarity:** As marked on body

### MAXIMUM RATINGS ( $T_A = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	DF005M	DF01M	DF02M	DF04M	DF06M	DF08M	DF10M	UNIT
Device marking code		DF005	DF01	DF02	DF04	DF06	DF08	DF10	
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forward output rectified current at $T_A = 40$ °C	$I_{F(AV)}$	1.0							A
Peak forward surge current single sine-wave superimposed on rated load	$I_{FSM}$	50							A
Rating for fusing ( $t < 8.3$ ms)	$I^2t$	10							A <sup>2</sup> s
Operating junction and storage temperature range	$T_J, T_{STG}$	- 55 to + 150							°C



<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)										
PARAMETER	TEST CONDITIONS	SYMBOL	DF005M	DF01M	DF02M	DF04M	DF06M	DF08M	DF10M	UNIT
Maximum instantaneous forward voltage drop per diode	1.0 A	$V_F$				1.1				V
Maximum reverse current at rated DC blocking voltage per diode	$T_A = 25\text{ }^\circ\text{C}$ $T_A = 125\text{ }^\circ\text{C}$	$I_R$				5.0 500				$\mu\text{A}$
Typical junction capacitance per diode	4.0 V, 1 MHz	$C_J$				25				pF

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)										
PARAMETER	SYMBOL	DF005M	DF01M	DF02M	DF04M	DF06M	DF08M	DF10M	UNIT	
Typical thermal resistance <sup>(1)</sup>	$R_{\theta JA}$ $R_{\theta JL}$				40 15				$^\circ\text{C/W}$	

**Note:**

(1) Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.5 x 0.5" (13 x 13 mm) copper pads

<b>ORDERING INFORMATION</b> (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
DF06M-E3/45	0.416	45	50	Tube

## RATINGS AND CHARACTERISTICS CURVES

( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

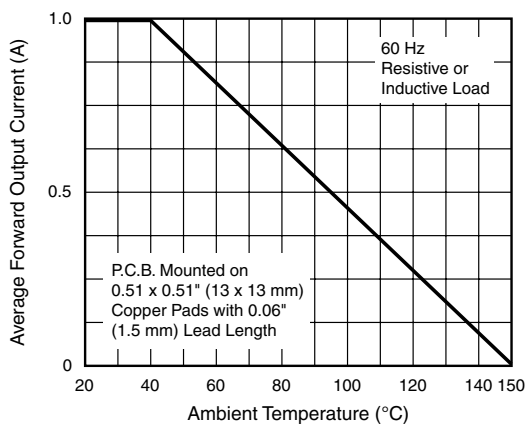


Figure 1. Derating Curve Output Rectified Current

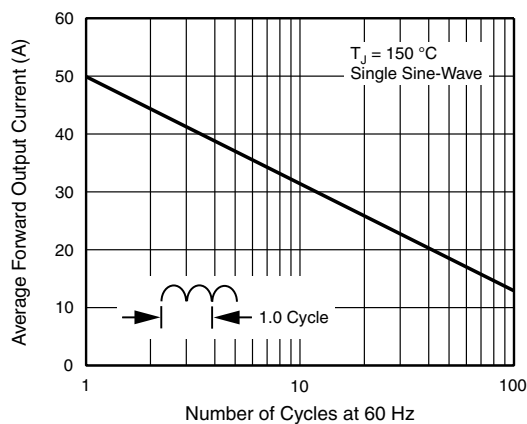


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

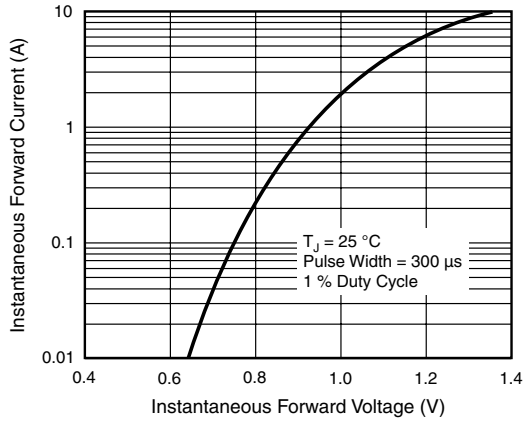


Figure 3. Typical Forward Characteristics Per Diode

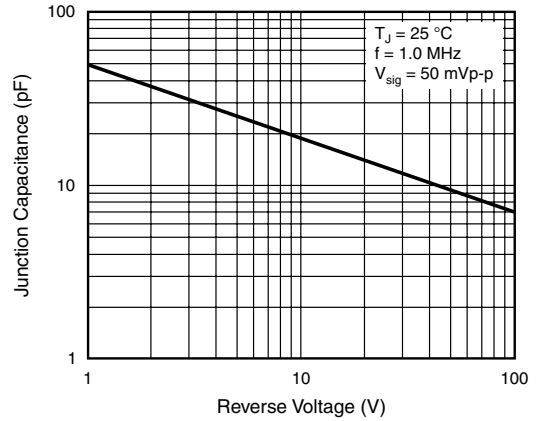


Figure 5. Typical Junction Capacitance Per Diode

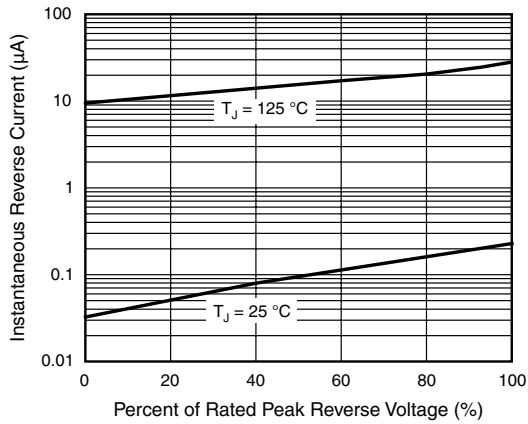


Figure 4. Typical Reverse Leakage Characteristics Per Diode

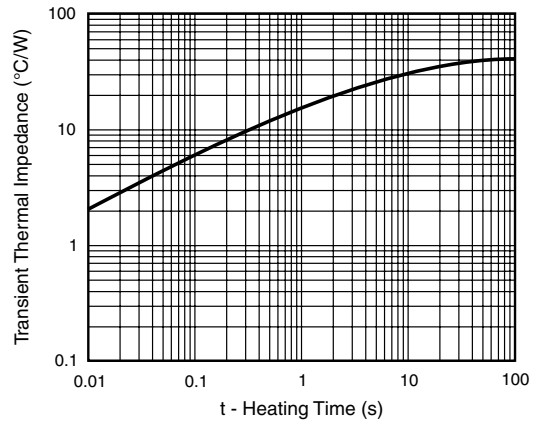


Figure 6. Typical Transient Thermal Impedance

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

**Case Style DFM**

